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PHOTOCOUPLER

PS9552,PS9552L1,PS9552L2,PS9552L3

2.5 A OUTPUT CURRENT, HIGH CMR IGBT GATE DRIVE PHOTOCOUPLER 8-PIN DIP PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS9552, PS9552L1, PS9552L2 and PS9552L3 are optically coupled isolators containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

The PS9552 Series is designed specifically for high common mode transient immunity (CMR), high output current and high switching speed.

The PS9552 Series is suitable for driving IGBTs and MOS FETs.

The PS9552 Series is in a plastic DIP (Dual In-line Package).

The PS9552L1 is lead bending type for long creepage distance.

The PS9552L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

The PS9552L3 is lead bending type (Gull-wing) for surface mounting.

FEATURES

- Long creepage distance (8 mm MIN.: PS9552L1, PS9552L2)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching (tPLH, tPHL = 0.5 μs MAX.)
- · UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CMH, CML = $\pm 25 \text{ kV/}\mu\text{s MIN.}$)
- Ordering number of tape product: PS9552L2-E3: 1 000 pcs/reel

: PS9552L3-E3: 1 000 pcs/reel

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- · Pb-Free product
- Safety standards
 - UL approved: No. E72422
 - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
 - BSI approved: No. 8937, 8938SEMKO approved: No. 615433
 - · NEMKO approved: No. P06207243
 - · DEMKO approved: No. 314091
 - · FIMKO approved: No. FI 22827

DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40019182 (Option)

APPLICATIONS

- · IGBT, Power MOS FET Gate Driver
- Industrial inverter
- · IH (Induction Heating)

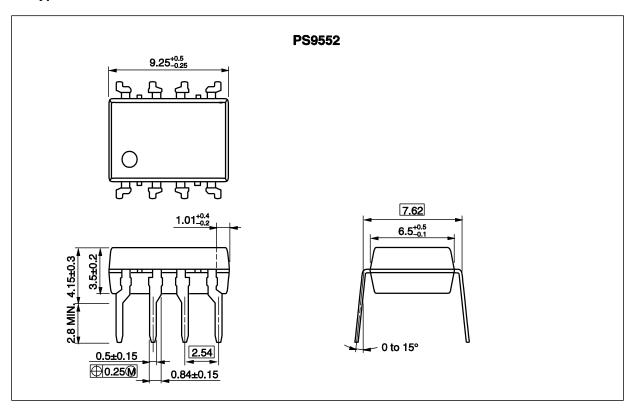
PIN CONNECTION
(Top View)

8 7 6 5
1. NC
2. Anode
3. Cathode
4. NC
5. Vee
6. Vo
7. Vo
8. Vcc

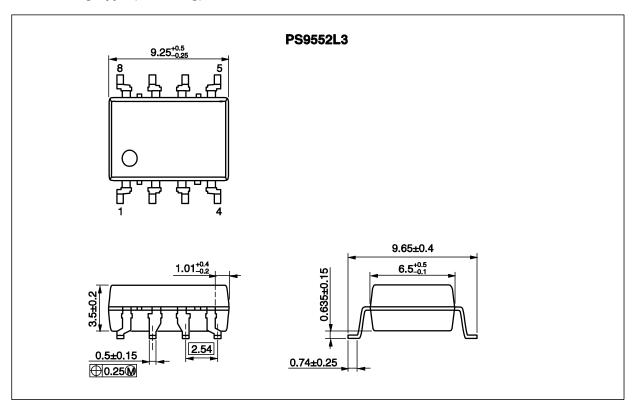
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<R> PACKAGE DIMENSIONS (UNIT: mm)

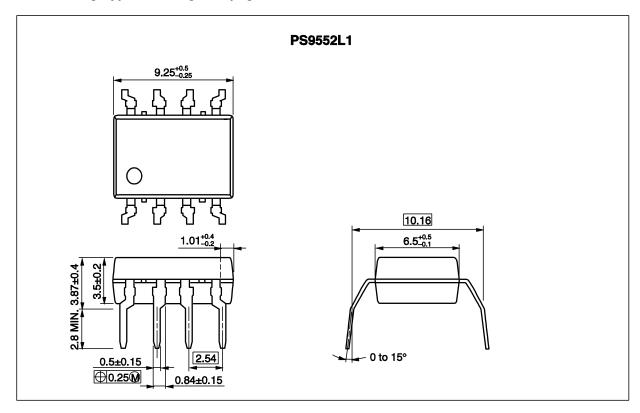
DIP Type



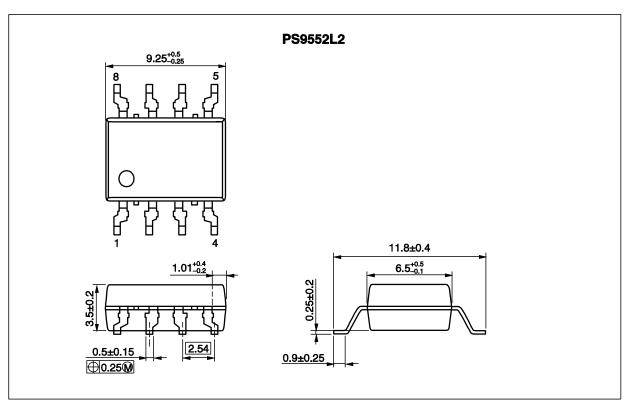
Lead Bending Type (Gull-wing) For Surface Mount



Lead Bending Type For Long Creepage Distance



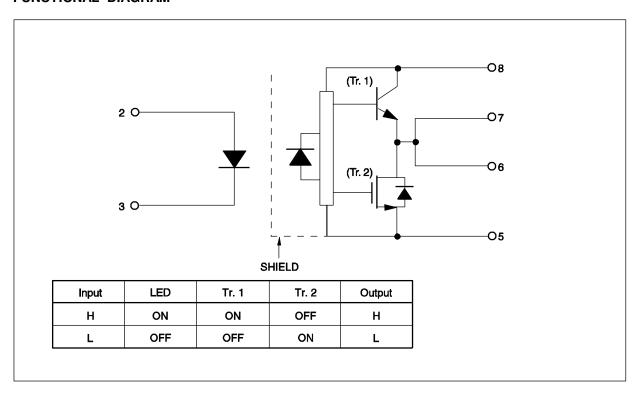
Lead Bending Type (Gull-wing) For Long Creepage Distance (Surface Mount)



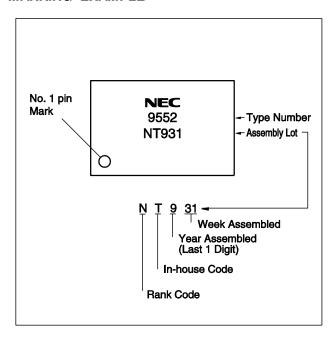
PHOTOCOUPLER CONSTRUCTION

| Parameter | PS9552, PS9552L3 | PS9552L1, PS9552L2 |
|--------------------------------|------------------|--------------------|
| Air Distance (MIN.) | 7 mm | 8 mm |
| Outer Creepage Distance (MIN.) | 7 mm | 8 mm |
| Isolation Distance (MIN.) | 0.4 mm | 0.4 mm |

FUNCTIONAL DIAGRAM



<R> MARKING EXAMPLE



ORDERING INFORMATION

| Part Number | Order Number | Solder Plating Specification | Packing Style | Safety Standard Approval | Application Part Number* ¹ |
|---------------|------------------|---------------------------------|------------------------------|-----------------------------|--|
| PS9552 | PS9552-AX | Pb-Free | Magazine case 50 pcs | Standard products | PS9552 |
| PS9552L1 | PS9552L1-AX | (Ni/Pd/Au) | | (UL, CSA, BSI, | PS9552L1 |
| PS9552L2 | PS9552L2-AX | | | SEMKO, NEMKO, | PS9552L2 |
| PS9552L3 | PS9552L3-AX | | | DEMKO, FIMKO | PS9552L3 |
| PS9552L2-E3 | PS9552L2-E3-AX | | Embossed Tape 1 000 pcs/reel | approved) | PS9552L2 |
| PS9552L3-E3 | PS9552L3-E3-AX | | | | PS9552L3 |
| PS9552-V | PS9552-V-AX | | Magazine case 50 pcs | DIN EN60747-5-2 | PS9552 |
| PS9552L1-V | PS9552L1-V-AX | | | (VDE0884 Part2) | PS9552L1 |
| PS9552L2-V | PS9552L2-V-AX | | | Approved (Option) | PS9552L2 |
| PS9552L3-V | PS9552L3-V-AX | | | | PS9552L3 |
| PS9552L2-V-E3 | PS9552L2-V-E3-AX | | Embossed Tape 1 000 pcs/reel | | PS9552L2 |
| PS9552L3-V-E3 | PS9552L3-V-E3-AX | | | | PS9552L3 |

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

| | Parameter | Symbol | Ratings | Unit |
|-------------------------------|--|------------------|-------------|---------|
| Diode | Forward Current | lF | 25 | mA |
| | Peak Transient Forward Current (Pulse Width < 1 \(\mu \sigma \) | IF (TRAN) | 1.0 | А |
| | Reverse Voltage | VR | 5 | V |
| Detecto r | High Level Peak Output Current ^{*1} | Іон (реак) | 2.5 | А |
| | Low Level Peak Output Current ^{*1} | IOL (PEAK) | 2.5 | Α |
| | Supply Voltage | (Vcc - Vee) | 0 to 35 | V |
| | Output Voltage | Vo | 0 to Vcc | V |
| | Power Dissipation*2 | Pc | 250 | mW |
| Isolation | Voltage *3 | BV | 5 000 | Vr.m.s. |
| Total Pov | wer Dissipation*4 | Рт | 300 | mW |
| Operating Frequency *5 | | f | 50 | kHz |
| Operating Ambient Temperature | | Та | -40 to +100 | °C |
| Storage Temperature | | T _{stg} | -55 to +125 | °C |

- *1 Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%
- *2 Reduced to 4.8 mW/ $^{\circ}$ C at T_A = 70 $^{\circ}$ C or more.
- *3 AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.
- *4 Reduced to 5.4 mW/ $^{\circ}$ C at T_A = 70 $^{\circ}$ C or more.
- *5 IOH (PEAK) ≤ 2.0 A ($\leq 0.3~\mu$ s), IOL (PEAK) ≤ 2.0 A ($\leq 0.3~\mu$ s)

RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|-------------------------------|-------------|------|------|------|------|
| Supply Voltage | (Vcc - Vee) | 15 | | 30 | V |
| Forward Current (ON) | IF (ON) | 7 | 10 | 16 | mA |
| Forward Voltage (OFF) | VF (OFF) | -2 | | 0.8 | V |
| Operating Ambient Temperature | Та | -40 | | 100 | °C |

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ELECTRICAL CHARACTERISTICS ($T_A = -40 \text{ to } +100^{\circ}\text{C}$, $V_{CC} = 15 \text{ to } 30 \text{ V}$, $I_{F(ON)} = 7 \text{ to } 16 \text{ mA}$, $V_{F(OFF)} = -2 \text{ to } 0.8 \text{ V}$, $V_{EE} = GND$, unless otherwise specified)

| | Parameter | Symbol | Conditions | MIN. | TYP.*1 | MAX. | Unit |
|----------|---|---------------------|--|-----------|-----------|----------|------|
| Diode | Forward Voltage | VF | IF = 10 mA, T _A = 25°C | 1.3 | 1.65 | 2.1 | V |
| | Input Capacitance | CIN | f = 1 MHz, V _F = 0 V, T _A = 25°C | | 30 | | pF |
| Detector | High Level Output Current | Іон | Vo = (Vcc - 4 V)*2 | 0.5 | 2.0 | | Α |
| | | | Vo = (Vcc – 15 V)*3 | 2.0 | | | |
| | Low Level Output Current | Ю | Vo = (VEE + 2.5 V)*2 | 0.5 | 2.0 | | Α |
| | | | Vo = (VEE + 15 V)*3 | 2.0 | | | |
| | High Level Output Voltage | Vон | lo = -100 mA*4 | Vcc - 3.5 | Vcc - 2.5 | Vcc- 1.5 | V |
| | Low Level Output Voltage | Vol | lo = 100 mA | | 0.1 | 0.5 | V |
| | High Level Supply Current | Іссн | Vo = open, I _F = 7 to 16 mA | | 2.0 | 5.0 | mA |
| | Low Level Supply Current | Iccl | Vo = open, V _F = -2 to +0.8 V | | 2.0 | 5.0 | mA |
| | UVLO Threshold | V _{UVLO+} | Vo > 5 V, IF = 10 mA | 11.0 | 12.3 | 13.5 | V |
| | | Vuvlo- | | 9.5 | 10.7 | 12.0 | |
| | UVLO Hysteresis | UVLO _{HYS} | Vo > 5 V, IF = 10 mA | | 1.6 | | V |
| Coupled | Threshold Input Current $(L \rightarrow H)$ | lflн | Io = 0 mA, Vo > 5 V | | 2.0 | 5.0 | mA |
| | Threshold Input Voltage $(H \rightarrow L)$ | VFHL | lo = 0 mA, Vo < 5 V | 0.8 | | | V |

^{*1} Typical values at $T_A = 25^{\circ}C$.

^{*2} Maximum pulse width = 50 μ s, Maximum duty cycle = 0.5%.

^{*3} Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%

^{*4} VoH is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).

SWITCHING CHARACTERISTICS (Ta = -40 to +100 °C, Vcc = 15 to 30 V, I_F (ON) = 7 to 16 mA, V_F (OFF) = -2 to 0.8 V, Vee = GND, unless otherwise specified)

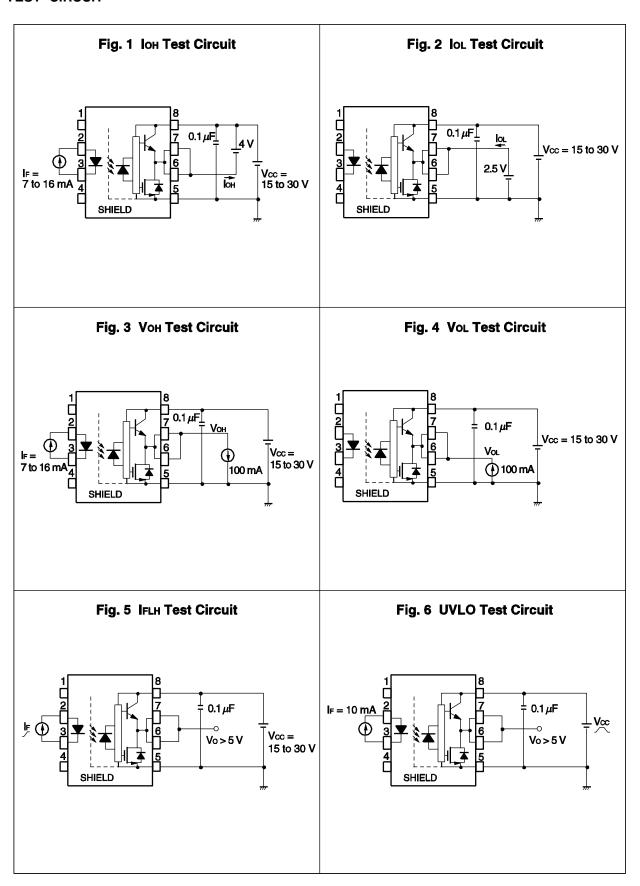
| Parameter | Symbol | Conditions | MIN. | TYP.*1 | MAX. | Unit |
|--|------------------|--|-------|--------|------|-------|
| Propagation Delay Time $(L \rightarrow H)$ | t PLH | $R_g=10~\Omega,~C_g=10~nF,~f=10~kHz,$ | 0.1 | 0.3 | 0.5 | μs |
| Propagation Delay Time $(H \rightarrow L)$ | t PHL | Duty Cycle = 50%*2, I _F = 7 to 16 mA | 0.1 | 0.3 | 0.5 | μs |
| Pulse Width Distortion (PWD) | tрнц—tрцн | | | | 0.3 | μs |
| Propagation Delay Time (Difference Between Any Two Products) | tрнц—tрцн | | -0.35 | | 0.35 | μs |
| Rise Time | tr | | | 0.1 | | μs |
| Fall Time | tr | | | 0.1 | | μs |
| UVLO (Turn On Delay) | t uvlo on | Vo > 5 V, IF = 10 mA | | 0.8 | | μs |
| UVLO (Turn Off Delay) | tuvlo off | Vo < 5 V, IF = 10 mA | | 0.6 | | μs |
| Common Mode Transient Immunity at High Level Output*3 | СМн | $T_{A} = 25^{\circ}C, \text{ IF} = 10 \text{ to } 16 \text{ mA}, \text{ Vcc} = 30 \text{ V}, \\ V_{O \text{ (MIN.)}} = 26 \text{ V}, \text{ Vcm} = 1.5 \text{k V}$ | 25 | | | kV/μs |
| Common Mode Transient Immunity at Low Level Output ^{*3} | CML | Ta = 25°C, IF = 0 mA, Vcc = 30 V, Vo (MAX) = 1 V, VcM = 1.5k V | 25 | | | kV/μs |

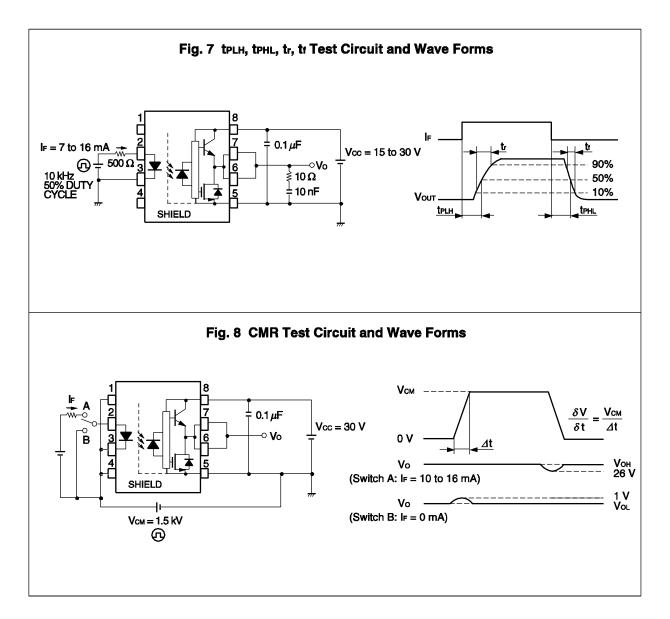
^{*1} Typical values at $T_A = 25^{\circ}C$.

^{*2} This load condition is equivalent to the IGBT load at 1 200 V/75 A.

^{*3} Connect pin 1 and pin 4 to the LED common.

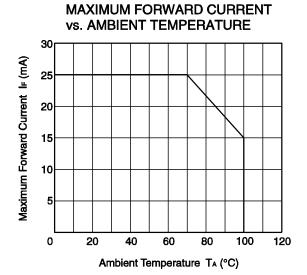
TEST CIRCUIT



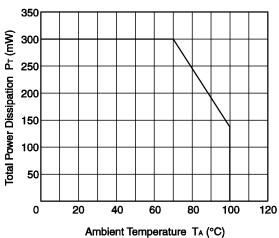


Remark CMR Test: Connect pin 1 and pin 4 to the LED common.

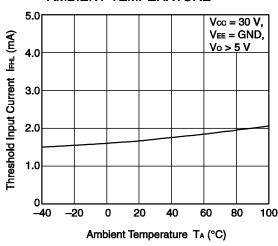
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



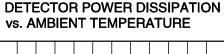


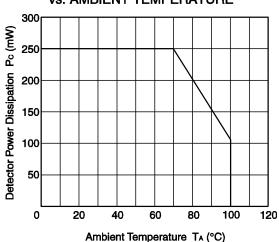


THRESHOLD INPUT CURRENT vs. **AMBIENT TEMPERATURE**

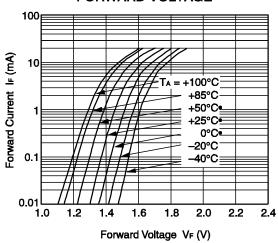


Remark The graphs indicate nominal characteristics.

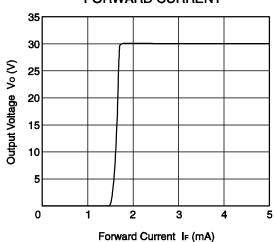


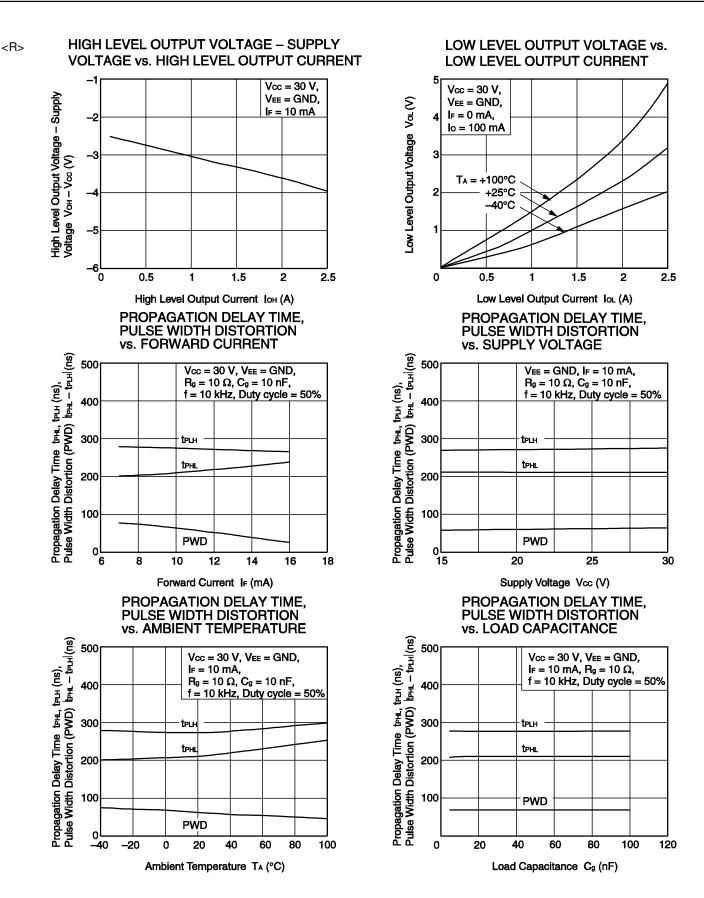


FORWARD CURRENT vs. **FORWARD VOLTAGE**

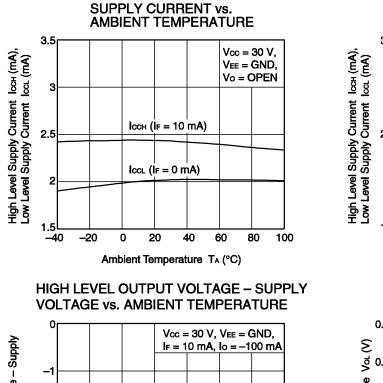


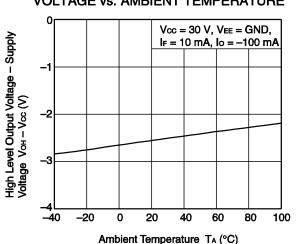
OUTPUT VOLTAGE vs. FORWARD CURRENT

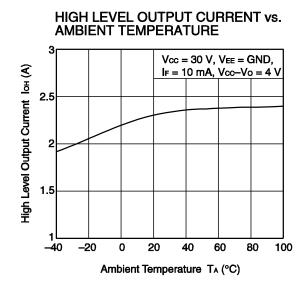


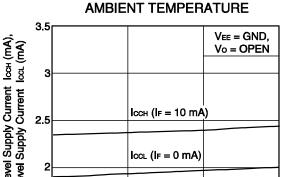


Remark The graphs indicate nominal characteristics.









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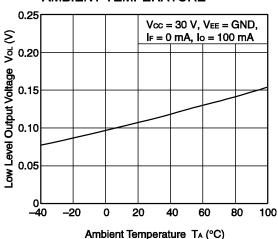
SUPPLY CURRENT vs.



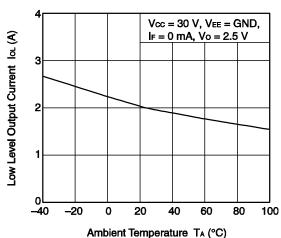
Supply Voltage Vcc (V)

25

30







Remark The graphs indicate nominal characteristics.

PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. LOAD RESISTANCE Propagation Delay Time тън, тъгн (ns), Pulse Width Distortion (PWD) тън – тъгн (ns) 500 Vcc = 30 V, VEE = GND, $I_F = 10 \text{ mA}, C_9 = 10 \text{ nF},$ f = 10 kHz, Duty cycle = 50%400 300 tplh **t**PHL 200 100 **PWD** ٥L

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Remark The graphs indicate nominal characteristics.

30

Load Resistance $R_g(\Omega)$

40

50

60

0

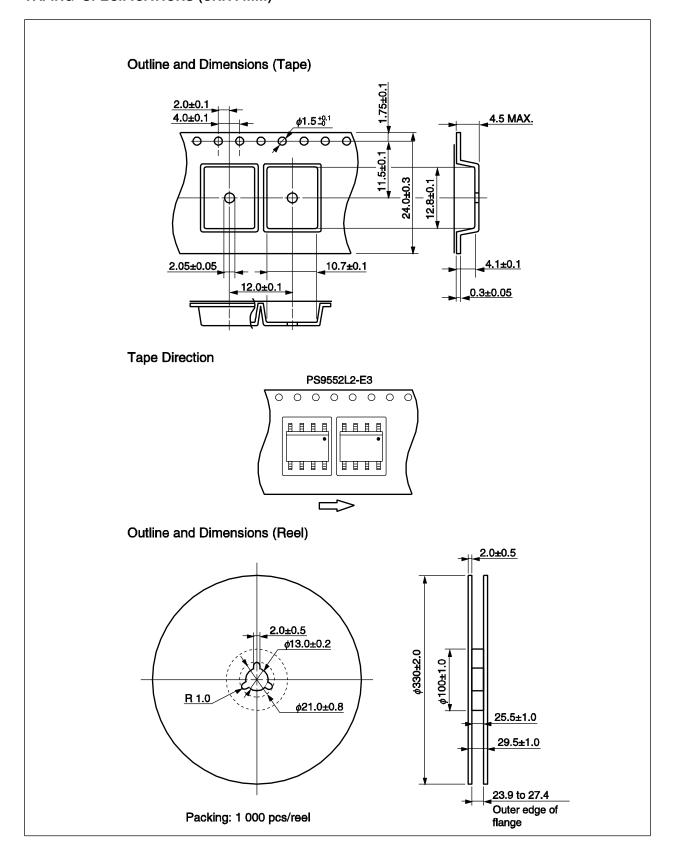
OUTPUT VOLTAGE vs. SUPPLY VOLTAGE 12 Output Voltage Vo (V) 10 8 **UVLO**HYS 6 . Vuvlo+ | (12.3 V) Vuvlo--(10.7 V)

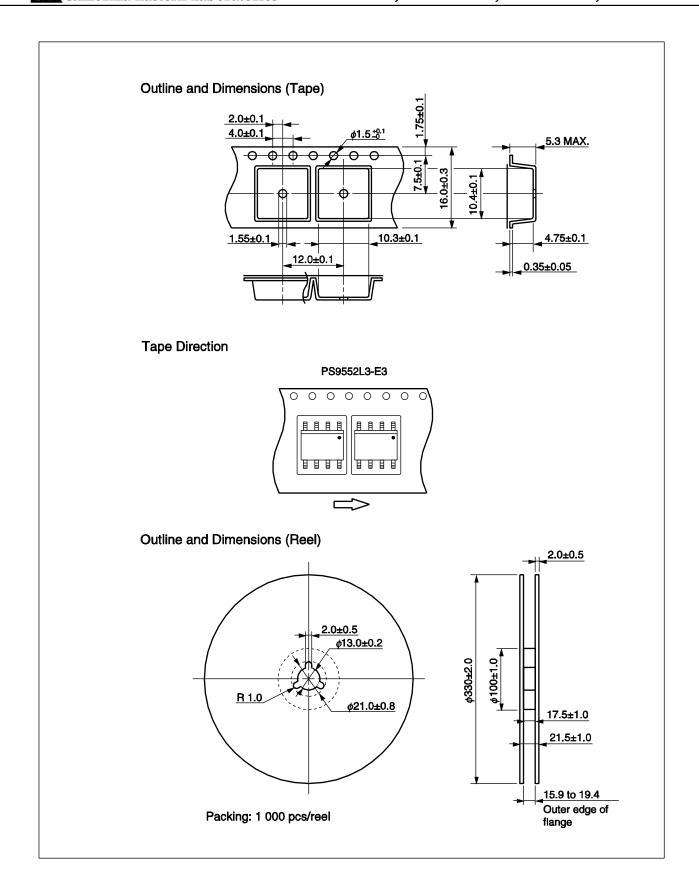
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Supply Voltage Vcc - VEE (V)

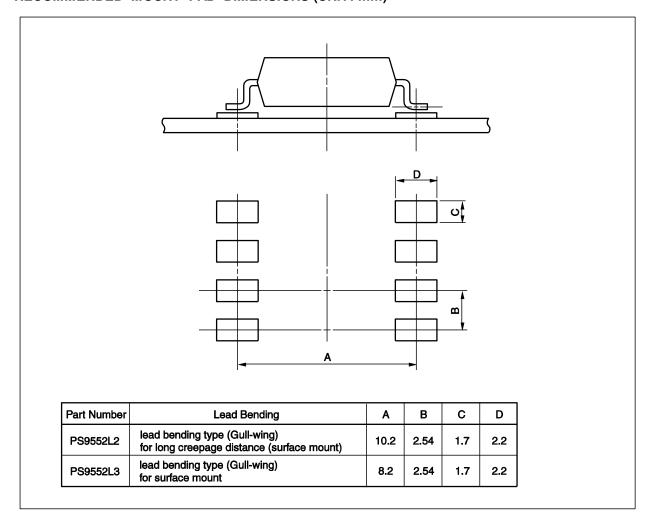
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TAPING SPECIFICATIONS (UNIT: mm)





RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

· Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

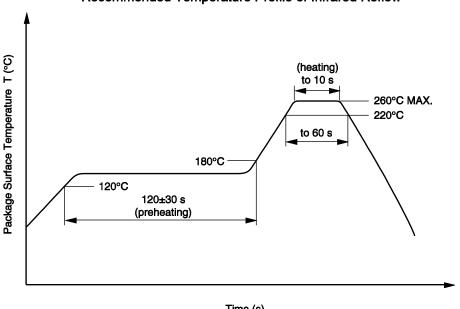
• Time to preheat temperature from 120 to 180°C 120±30 s

· Number of reflows Three

 Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

350°C or below • Peak Temperature (lead part temperature) • Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. Board designing
 - (1) By-pass capacitor of more than 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
 - (2) In older to avoid malfunctions and characteristics degradation, IGBT collector or emitter traces should not be closed to the LED input.
 - (3) Pins 1, 4 (which is an NC^{*1} pin) can either be connected directly to the GND pin on the LED side or left open.

Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.

- *1 NC: Non-Connection (No Connection)
- 3. Make sure the rise/fall time of the forward current is 0.5 μ s or less.
- **4.** In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is $3 \text{ V}/\mu\text{s}$ or less.
- 5. Avoid storage at a high temperature and high humidity.

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<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter | Symbol | Spec. | Unit |
|--|----------------------|--------------------------------------|--|
| Climatic test class (IEC 60068-1/DIN EN 60068-1) | | 55/100/21 | |
| Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{\text{IORM}}, P_{\text{d}} < 5 \text{pC}$ | UIORM Upr | 1 130 1 695 | V _{peak} V _{peak} |
| Test voltage (partial discharge test, procedure b for all devices) $U_{pr}=1.875\times U_{\text{IORM}},P_{\text{d}}<5\;p\text{C}$ | Upr | 2 119 | V_{peak} |
| Highest permissible overvoltage | Utr | 8 000 | V _{peak} |
| Degree of pollution (DIN EN 60664-1 VDE0110 Part 1) | | 2 | |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11)) | CTI | 175 | |
| Material group (DIN EN 60664-1 VDE0110 Part 1) | | III a | |
| Storage temperature range | T _{stg} | -55 to +125 | °C |
| Operating temperature range | Та | -40 to +100 | °C |
| Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at T}_{A} = 25^{\circ}\text{C}$ $V_{IO} = 500 \text{ V dc at T}_{A} \text{ MAX. at least } 100^{\circ}\text{C}$ | Ris MIN. Ris MIN. | 10 ¹² 10 ¹¹ | Ω Ω |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current IF, Psi = 0) Power (output or total power dissipation) Isolation resistance | Tsi Isi Psi | 175 400 700 | °C mA mW |
| $V_{IO} = 500 \text{ V dc}$ at $T_A = Tsi$ | Ris MIN. | 10 ⁹ | Ω |

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 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

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(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).

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GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.